TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX74F,TC74LVX74FN,TC74LVX74FT

Dual D-Type Flip-Flop with Preset and Clear

The TC74LVX74F/ FN/ FT is a high-speed CMOS D-flip flop fabricated with silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This device is suitable for low-voltage and battery operated systems.

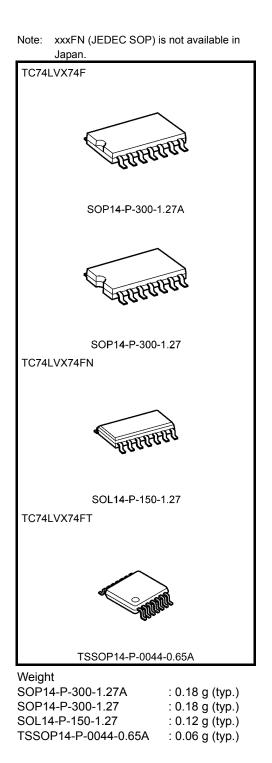
The signal level applied to the D input is transferred to Q output during the positive going transition of the CK pulse.

 $\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the CK and are accomplished by setting the appropriate input low.

An input protection circuit ensures that 0 to 5.5V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

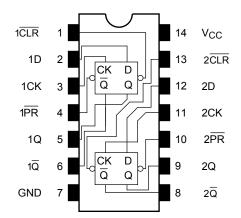
Features

- High-speed: $f_{max} = 145 \text{ MHz}$ (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: $I_{CC} = 2 \mu A (max) (Ta = 25^{\circ}C)$
- Input voltage level: V_{IL} = 0.8 V (max) (V_{CC} = 3 V)
 - $V_{IH} = 2.0 V (min) (V_{CC} = 3 V)$
- Power-down protection provided on all inputs
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74HC74

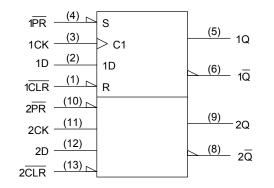


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Pin Assignment (top view)



IEC Logic Symbol



Truth Table

Inputs			Outputs			Function		
CLR	\overline{PR}	D	СК	Q	IQ	T difetion		
L	Н	Х	Х	L	Н	Clear		
Н	L	х	Х	Н	L	Preset		
L	L	Х	Х	Н	Н	—		
Н	Н	L		L	Н	—		
Н	Н	Н		Н	L	—		
Н	Н	Х	\rightarrow	Qn	Qn	No change		

X: Don't care

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	V
DC output voltage	V _{OUT}	-0.5 to V_{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	IOUT	±25	mA
DC V _{CC} /ground current	ICC	±50	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics		Sym- bol Test Condition		Ta = 25°C		Ta = −40 to 85°C		Unit			
					$V_{CC}(V)$	Min	Тур.	Max	Min	Max	
					2.0	1.5	_	—	1.5	_	
	H-level	VIH		_	3.0	2.0	_	_	2.0	_	
					3.6	2.4	_	_	2.4	_	V
Input voltage	L-level	V _{IL}	_		2.0	_	_	0.5	_	0.5	
					3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	2.0	_	1.9	_	
				I _{OH} = -50 μA	3.0	2.9	3.0	_	2.9	_	
Output voltage				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	v
Output voltage				I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	v
	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 50 μA	3.0	_	0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
Input leakage current		I _{IN}	V _{IN} = 5.5 V or GND		3.6	_	_	±0.1		±1.0	μA
Quiescent supply cu	irrent	ICC	$V_{IN} = V_{CC}$ or GND		3.6	_	_	2.0		20.0	μA

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition	ondition		Ta = −40 to 85°C	Unit	
			V _{CC} (V)	Limit	Limit		
Minimum pulse width	t _{W (L)}		2.7	8.5	10.0	ns	
(CK)	tw (H)	_	$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum pulse width	• • • • • •		2.7	8.5	10.0	ns	
(CLR , PR)	t _{W (L)}	—	$\textbf{3.3}\pm\textbf{0.3}$	6.0	7.0		
Minimum set-up time	+		2.7	8.0	9.5	ns	
Winimum set-up time	t _s		$\textbf{3.3}\pm\textbf{0.3}$	5.5	6.5	115	
Minimum hold time	t .		2.7	0.5	0.5	ns	
	t _h	—	$\textbf{3.3}\pm\textbf{0.3}$	0.5	0.5		
Minimum removal time	+		2.7	6.5	7.5	200	
(CLR , PR)	t _{rem}		$\textbf{3.3}\pm\textbf{0.3}$	5.0	5.0	ns	

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition			Ta = 25°C		Ta = -40 to 85°C		Unit	
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
	t		2.7	15	_	7.3	15.0	1.0	18.5	- ns
Propagation delay time	t _{pLH}		2.1	50		9.8	18.5	1.0	22.0	
(CK-Q, Q)	t-1.0		3.3 ± 0.3	15		5.7	9.7	1.0	11.5	
	t _{pHL}		3.3 ± 0.3	50		8.2	13.2	1.0	15.0	
	t _{pLH}	_	2.7	15		8.4	15.6	1.0	18.5	- ns - MHz
Propagation delay time				50		10.9	19.1	1.0	22.0	
$(\overline{CLR}, \overline{PR} - Q, \overline{Q})$	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	15		6.6	10.1	1.0	12.0	
				50	_	9.1	13.6	1.0	15.5	
			2.7	15	55	135		50		
Maximum clock frequency	f			50	45	60	_	40	_	
	f _{max}		3.3 ± 0.3	15	95	145	_	80	_	
				50	60	85	_	50	_	
Output to output skew	t _{osLH}	(Note 1)	2.7	50	_		1.5	—	1.5	ns
	t _{osHL}		$\textbf{3.3}\pm\textbf{0.3}$	50	_		1.5		1.5	115
Input capacitance	C _{IN}			(Note 2)	_	4	10	—	10	pF
Power dissipation capacitance	C _{PD}			(Note 3)	_	25	_			pF

Note 1: Parameter guaranteed by design. $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Note 2: Parameter guaranteed by design.

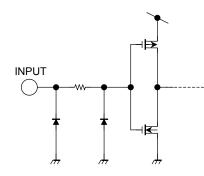
Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation: $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per F/F)

Noise Characteristics (Ta = 25° C, input: t_r = t_f = 3 ns, C_L = 50 pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V_{OL}	V _{OLP}	_	3.3	0.3	0.5	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	_	3.3	-0.3	-0.5	V
Minimum high level dynamic input voltage V_{IH}	VIHD	_	3.3	_	2.0	V
Maximum low level dynamic input voltage V_{IL}	VILD	_	3.3	_	0.8	V

Input Equivalent Circuit

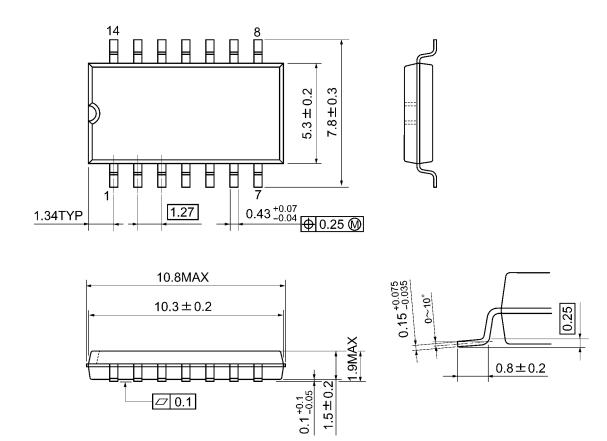




Package Dimensions

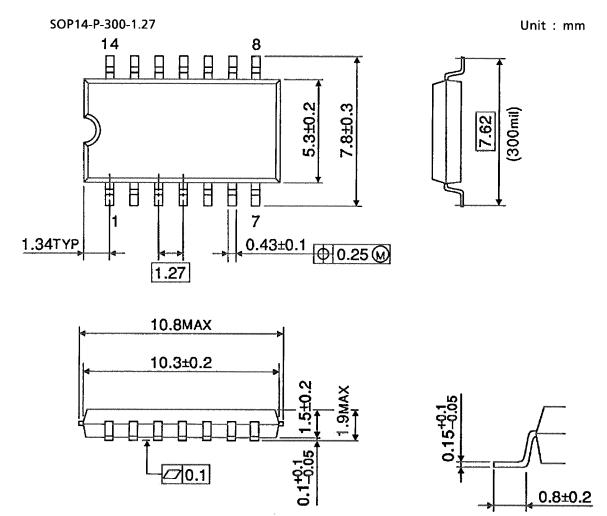
SOP14-P-300-1.27A

Unit: mm



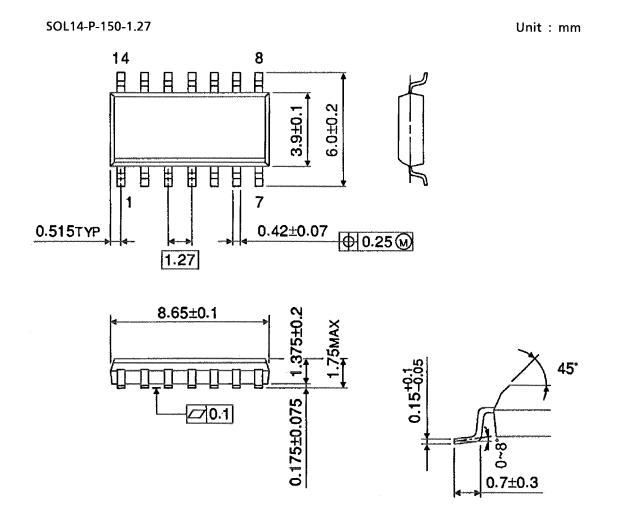
Weight: 0.18 g (typ.)

Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)



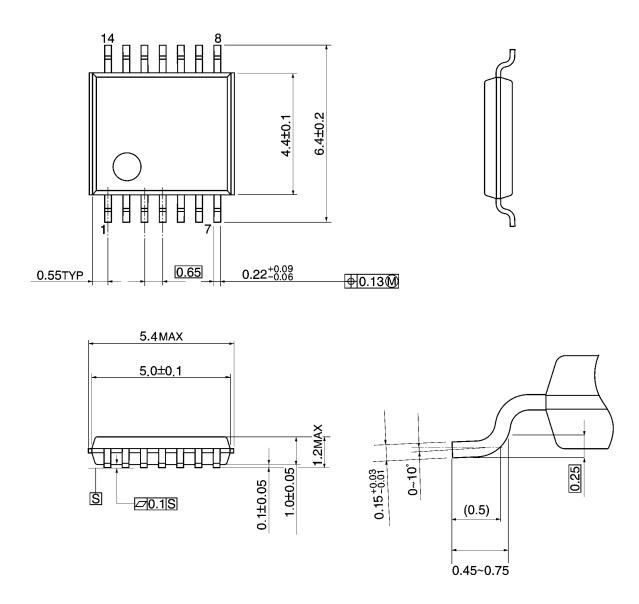
Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

Note: Lead (Pb)-Free Packages SOP14-P-300-1.27A SOL14-P-150-1.27 TSSOP14-P-0044-0.65A

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